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RoHS COMPLIANT

N-Channel 60 V (D-S) MOSFET

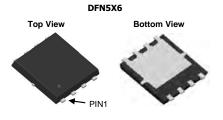
PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (mΩ)(Typ.)	I _D (A) ^{a, e}	Q _g (Typ.)		
60	1.8 at V _{GS} = 10 V	180	105 nC		
	2.8 at V_{GS} = 4.5 V	100	100110		

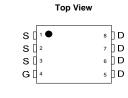
FEATURES

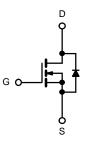
- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested

APPLICATIONS

- Notebook PC Core
- VRM/POL







N-Channel MOSFET

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V _{GS}	± 20		
	T _C = 25 °C		180 ^{a, e}	A	
Continuous Drain Current (T _J = 175 °C)	T _C = 70 °C	1-	160 ^e		
Commodus Drain Current $(T_j = TTS C)$	T _A = 25 °C	I _D	30 ^{b, c}		
	T _A = 70 °C		20 ^{b, c}		
Pulsed Drain Current		I _{DM}	720		
Avalanche Current Pulse	L = 0.1 mH	I _{AS}	175		
Single Pulse Avalanche Energy	L = 0.1 mm	E _{AS}	650	mJ	
Continuous Source-Drain Diode Current	T _C = 25 °C	I _S	180 ^{a, e}	A	
Continuous Source-Drain Diode Current	T _A = 25 °C	'5	4.69 ^{b, c}		
	T _C = 25 °C		250 ^a		
Maximum Power Dissipation	T _C = 70 °C	P _D	175	w	
	T _A = 25 °C	' D	7.5 ^{b, c}		
	T _A = 70 °C		5.3 ^{b, c}		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^{b, d}	$t \le 10 \text{ s}$	R _{thJA}	18	25	°C/W	
Maximum Junction-to-Case	Steady State	R _{thJC}	0.6	0.8	C/VV	

Notes:

a. Based on $T_C = 25$ °C. b. Surface mounted on 1" x 1" FR4 board.

c. t = 10 s. d. Maximum under steady state conditions is 90 °C/W. e. Calculated based on maximum junction temperature.

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Parameter	Symbol	Test Conditions	Min .	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_{D} = 250 \mu A$	60	-	-	V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = 250 μΑ	-	35	-	- mV/°C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	η = 200 μΛ	-	- 5.5	-		
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1.0		3.0	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	-		± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	-		1		
		$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 \text{ °C}$	-		10	μA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	180			А	
Drain-Source On-State Resistance ^a	R _{DS(on)} -	V _{GS} = 10 V, I _D = 30 A	-	1.8	2.5	mΩ	
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	-	2.8	3.6		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 5 V, I _D = 20 A	-	110		S	
Dynamic ^b							
Input Capacitance	C _{iss}		-	7080	-	pF	
Output Capacitance	C _{oss}	V_{DS} =30 V , V_{GS} = 0 V, f = 1 MHz	-	1440	-		
Reverse Transfer Capacitance	C _{rss}		-	3	-		
Total Gate Charge	Qg		-	105	-	nC	
Gate-Source Charge	Q _{gs}	V_{DS} = 30 V, V_{GS} = 10 V, I_{D} = 30 A	_	84	-		
Gate-Drain Charge	Q _{gd}		-	16	-		
Gate Resistance	Rg	f = 1 MHz	-	1.5	-	Ω	
Turn-On Delay Time	t _{d(on)}		-	19	-		
Rise Time	t _r	$V_{DD} = 30 \text{ V}, \text{ R}_{L} = 0.555\Omega$	-	20	-	ns	
Turn-Off Delay Time	t _{d(off)}	I_D =30 A, V_{GEN} = 10 V, R_g = 1 Ω	-	31	-		
Fall Time	t _f		-	6	-		
Drain-Source Body Diode Characteristic	s						
Continuous Source-Drain Diode Current	۱ _S	$T_{C} = 25 \ ^{\circ}C$	-		180	A	
Pulse Diode Forward Current ^a	I _{SM}		-		720		
Body Diode Voltage	V _{SD}	I _S = 20 A	-	0.8	1.2		
V Body Diode Reverse Recovery Time	t _{rr}		-	55	78	ns	
Body Diode Reverse Recovery Charge	Q _{rr}	I _F = 20 A, di/dt = 100 A/µs, T ₁ = 25 °C	-	97	170	nC	
Reverse Recovery Fall Time	t _a	$r_{\rm F} = 20.1$, $a_{\rm H} a_{\rm C} = 100.1$ upo, $r_{\rm J} = 20.0$	-	29		ns	
Reverse Recovery Rise Time	t _b		-	23			

Notes:

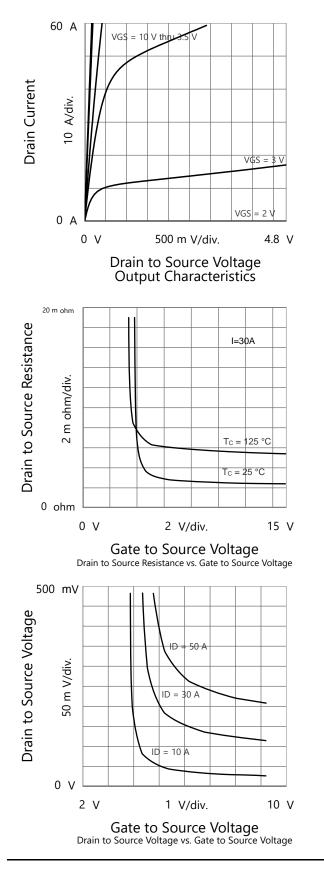
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

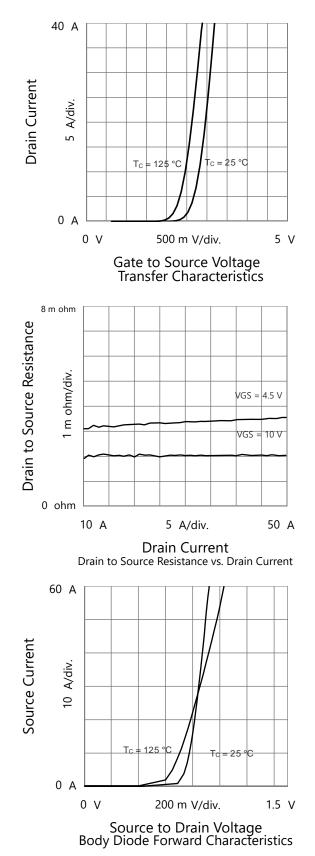
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



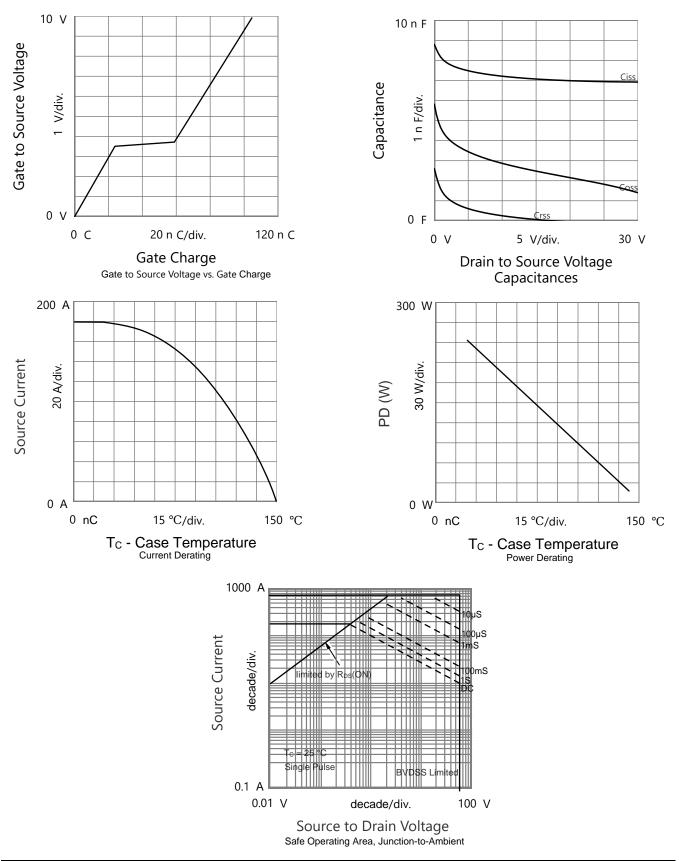
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)







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